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**Vishay Semiconductors** 

# **Small Signal Fast Switching Diodes**



#### FEATURES

- Silicon epitaxial planar diodes
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

• Extreme fast switches



#### **ADDITIONAL RESOURCES**



#### **MECHANICAL DATA**

Case: DO-35 (DO-204AH) Weight: approx. 125 mg Cathode band color: black

#### Packaging codes / options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

| PARTS TABLE |                       |              |                       |                          |  |  |
|-------------|-----------------------|--------------|-----------------------|--------------------------|--|--|
| PART        | ORDERING CODE         | TYPE MARKING | CIRCUIT CONFIGURATION | REMARKS                  |  |  |
| 1N4448      | 1N4448TAP or 1N4448TR | V4448        | Single                | Tape and reel / ammopack |  |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                  |                    |       |      |  |  |
|--|----------------------------------|--------------------|-------|------|--|--|
| PARAMETER  | TEST CONDITION                   | SYMBOL             | VALUE | UNIT |  |  |
| Repetitive peak reverse voltage  |                                  | V <sub>RRM</sub>   | 100   | V    |  |  |
| Reverse voltage  |                                  | V <sub>R</sub>     | 75    | V    |  |  |
| Peak forward surge current   | t <sub>p</sub> = 1 μs            | I <sub>FSM</sub>   | 2     | A    |  |  |
| Repetitive peak forward current  |                                  | I <sub>FRM</sub>   | 500   | mA   |  |  |
| Forward continuous current   |                                  | I <sub>F</sub>     | 300   | mA   |  |  |
| Average forward current  | V <sub>R</sub> = 0               | I <sub>F(AV)</sub> | 150   | mA   |  |  |
| Power dissipation  | l = 4 mm, T <sub>L</sub> = 45 °C | P <sub>tot</sub>   | 440   | mW   |  |  |
|  | l = 4 mm, T <sub>L</sub> ≤ 25 °C | P <sub>tot</sub>   | 500   | mW   |  |  |

| <b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |             |      |  |
|---|---|-------------------|-------------|------|--|
| PARAMETER   | TEST CONDITION                            | SYMBOL            | VALUE       | UNIT |  |
| Thermal resistance junction to ambient air  | $I = 4 \text{ mm}, T_L = \text{constant}$ | R <sub>thJA</sub> | 350         | K/W  |  |
| Junction temperature  |   | Tj                | 175         | °C   |  |
| Storage temperature range   |   | T <sub>stg</sub>  | -65 to +150 | °C   |  |

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1N4448

| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |       |      |       |      |
|---|--|-------------------|-------|------|-------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL            | MIN.  | TYP. | MAX.  | UNIT |
| Forward valtage   | I <sub>F</sub> = 5 mA  | V <sub>F</sub>    | 0.620 |      | 0.720 | V    |
| Forward voltage   | I <sub>F</sub> = 100 mA  | V <sub>F</sub>    |       |      | 1     | V    |
|   | V <sub>R</sub> = 20 V  | I <sub>R</sub>    |       |      | 25    | nA   |
| Reverse current   | V <sub>R</sub> = 20 V, T <sub>j</sub> = 150 °C   | I <sub>R</sub>    |       |      | 50    | μA   |
|   | V <sub>R</sub> = 75 V  | I <sub>R</sub>    |       |      | 5     | μA   |
| Breakdown voltage   | $I_{\rm R} = 100 \ \mu {\rm A}, \ t_{\rm p}/{\rm T} = 0.01, \ t_{\rm p} = 0.3 \ {\rm ms}$  | V <sub>(BR)</sub> | 100   |      |       | V    |
| Diode capacitance   | $V_{R} = 0, f = 1 \text{ MHz}, V_{HF} = 50 \text{ mV}$   | C <sub>D</sub>    |       |      | 4     | pF   |
| Rectification efficiency  | V <sub>HF</sub> = 2 V, f = 100 MHz   | ηr                | 45    |      |       | %    |
|   | I <sub>F</sub> = I <sub>R</sub> = 10 mA, i <sub>R</sub> = 1 mA   | t <sub>rr</sub>   |       |      | 8     | ns   |
| Reverse recovery time   | $\label{eq:IF} \begin{array}{l} I_{F} = 10 \text{ mA},  V_{R} = 6 \text{ V}, \\ i_{R} = 0.1 \text{ x } I_{R},  R_{L} = 100 \ \Omega \end{array}$ | t <sub>rr</sub>   |       |      | 4     | ns   |

TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

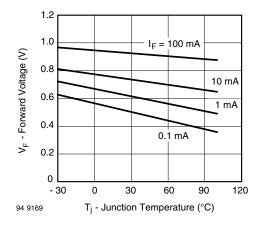


Fig. 1 - Forward Voltage vs. Junction Temperature

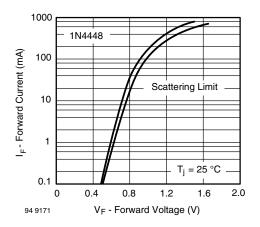


Fig. 2 - Forward Current vs. Forward Voltage

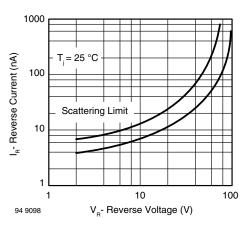


Fig. 3 - Reverse Current vs. Reverse Voltage

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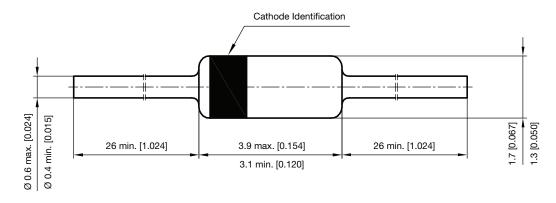
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### PACKAGE DIMENSIONS in millimeters (inches): DO-35 (DO-204AH)



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